

Description

The ACE7402A is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits where high-side switching, and low in-line power loss are needed in a very small outline surface mount package.

Features

- 20V/4.0A, $R_{DS(ON)}=65mΩ@VGS=4.5V$
- $20V/3.4A, R_{DS(ON)} = 80m \Omega @VGS = 2.5V$
- 20V/2.8A, R_{DS(ON)} =95m Ω @VGS=1.8V
- Super high density cell design for extremely low R_{DS (ON)}
- Exceptional on-resistance and maximum DC current capability

Application

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

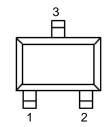


Absolute Maximum Ratings

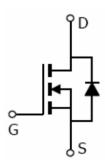
Parameter	Symbol	Max	Unit	
Drain-Source Voltage	V_{DSS}	20	٧	
Gate-Source Voltage	V_{GSS}	±12	٧	
Continuous Drain Current ($T_J=150^{\circ}$ C) $T_A=25^{\circ}$ C $T_A=70^{\circ}$ C		I_	2.4	Α
		I _D	1.7	^
Pulsed Drain Current	I _{DM}	6	Α	
Continuous Source Current (Diode Conduction)		I _S	1.6	Α
Power Dissipation		P _D	0.33	W
			0.21	VV
Operating Junction Temperature		T_J	-55/150	οС
Storage Temperature Range		T _{STG}	-55/150	°С
Thermal Resistance-Junction to Ambient		$R_{\theta JA}$	105	°C/W

Packaging Type

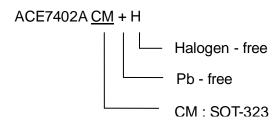




SOT-323	Description		
1	Gate		
2	Source		
3	Drain		



Ordering information





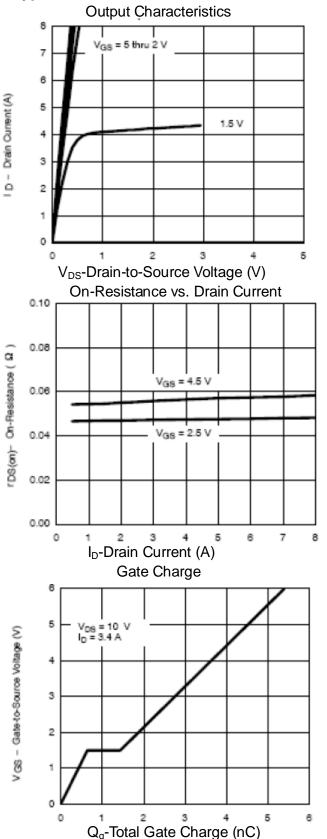
Electrical Characteristics

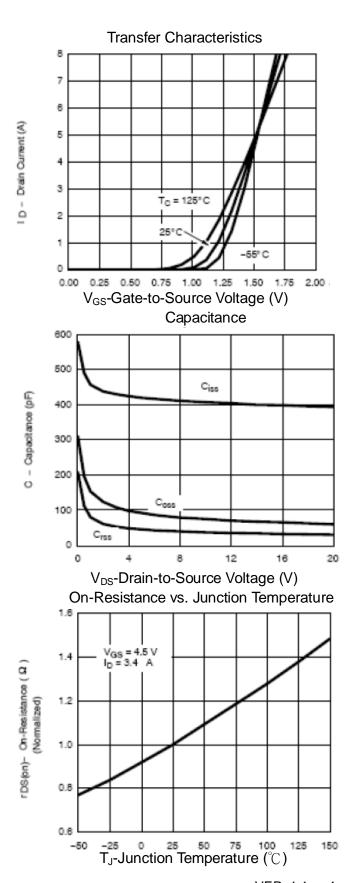
 $T_A=25^{\circ}C$, unless otherwise noted

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
	-	Static	<u>"</u>				
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250uA	20	20		V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA 0.35			0.85		
Gate Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 12V$			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =20V, V_{GS} =0V			1	^	
		V_{DS} =20V, V_{GS} =0V T_J =55 $^{\circ}$ C	V _{GS} =0V T _J =55°C		5	uA	
		$V_{DS}{\ge}5V$, V_{GS} =4.5 V	6			Α	
Drain-Source		V_{GS} =4.5V, I_D =4.0A		0.060	0.065		
	R _{DS(ON)}	V_{GS} =2.5V, I_{D} =3.4A V_{GS} =1.8V, I_{D} =2.8A		0.067	0.080	Ω	
On-Resistance				0.076	0.095		
Forward Transconductance	Gfs	V _{DS} =5V,I _D =-3.6A		10		S	
Diode Forward Voltage	V_{SD}	I _S =1.6A, V _{GS} =0V		0.8	1.2	V	
		Dynamic					
Total Gate Charge	Q_g			4.8	8		
Gate-Source Charge	Q_{gs}	V_{DS} =6V, V_{GS} =4.5V, I_{D} =2.8A		1.0		nC	
Gate-Drain Charge	Q_{gd}			1.0			
Input Capacitance	Ciss			485			
Output Capacitance	Coss	$V_{DS}=6V$, $V_{GS}=0V$, $f=1MHz$		85		nE	
Reverse Transfer Capacitance	Crss	VDS=OV, VGS=OV, I=TIVINZ		40		pF	
Turn-On Time	td(on)			8	14		
	tr	$V_{DD}=6V, R_{L}=6\Omega, V_{GEN}=4.5V,$		12	18		
T 0"T	td(off)	$I_D=1.0A$, $R_G=6\Omega$		30	35	nS	
Turn-Off Time	tf			12	16		



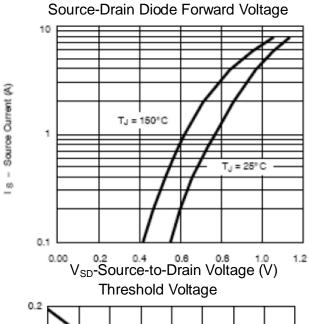
Typical Performance Characteristics

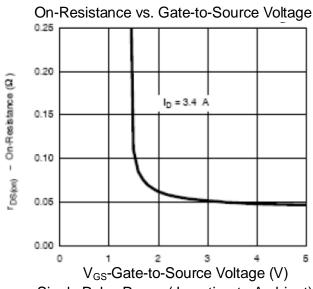


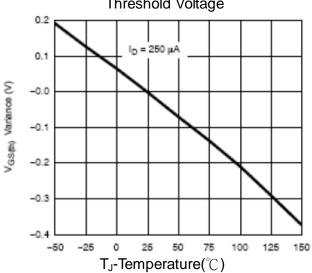


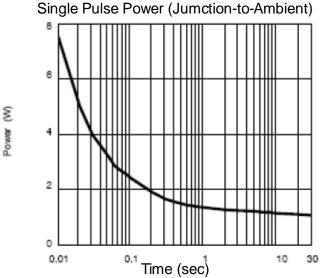


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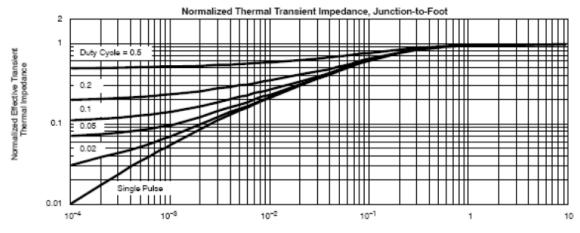








Normalized Thermal Transient Impedance, Junction-to Foot



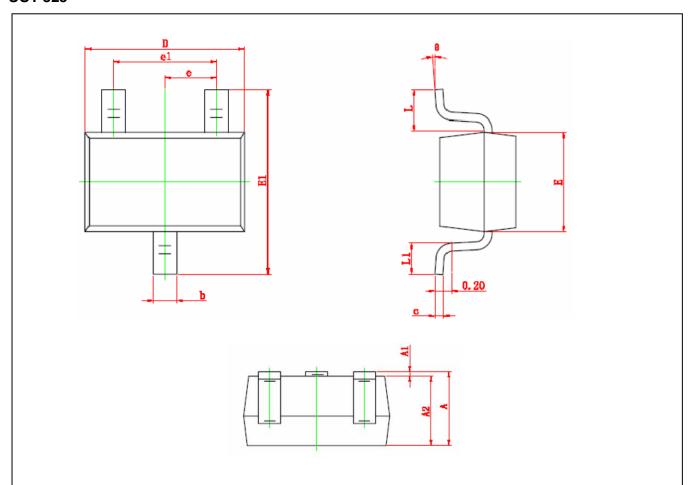
Square Wave Pulse Duration (sec)

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Packing Information

SOT-323



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650 TYP		0.026 TYP		
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.021 REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	



Notes

ACE does not assume any responsibility for use as critical components in life support devices or systems without the express written approval of the president and general counsel of ACE Electronics Co., LTD. As sued herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and shoes failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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